Maximum Ratings

Storage Temperature.....-65℃ to +150℃
Ambient Temperature with Power Applied.....-40℃ to +85℃
Supply Voltage V_{CC} .....-0.5V to +7.0V
DC Switch Voltage V_S .....-0.5V to +7.0V
DC Input Voltage V_{IN} .....-0.5V to +7.0V
DC Output Current V_{OUT}.....128mA
DC V_{CC} or Ground Current I_{CC} /I_{GND} .....±100mA
Junction Temperature under Bias (T_J) .....150℃
Junction Lead Temperature (T_L)
(Soldering, 10 seconds) .....260℃
ESD（HBM）.....5KV
Power Dissipation (P_D) @ +85℃ MSOP10 350mW

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{CC}	Operating Voltage	-	1.65	-	5.5	V
V_{IN}	Control Input Voltage	-	0	-	V_{CC}	V
V_S	Switch Input Voltage	-	0	-	5.5	V
V_{OUT}	Output Voltage	-	0	-	V_{CC}	V
T_A	Operating Temperature	-	-40	25	85	℃
t_r, t_f	Input Rise and Fall Time	Control Input V_{CC} = 2.7V to 3.6V	0	-	10	ns/V
		Control Input V_{CC} = 4.5V to 5.5V	0	-	5	ns/V

Note: Control input must be held HIGH or LOW; it must not float.

DC Electrical Characteristics

(T_A = –40℃ to 85℃, unless otherwise noted.)

Symbol	Parameter	Test Conditions	Supply Voltage	Min.	Typ.	Max.	Units
V_{IAR}	Analog Input Signal Range	-	V_{CC}	0	-	V_{CC}	V
R_{ON}	ON Resistance (1)	I_{Ax}=100mA, V_{nBx} =0V	V_{CC}=4.5V	-	0.7	1.1	Ω
		I_{Ax}=100mA, V_{nBx} =2.4V		-	0.6	1.0	
		I_{Ax}=100mA, V_{nBx} =4.5V		-	0.8	1.2	
		I_{Ax}=100mA, V_{nBx} =0V	V_{CC}=3.0V	-	0.8	1.3	Ω
		I_{Ax}=100mA, V_{nBx} =3.0V		-	0.9	1.9	
		I_{Ax}=100mA, V_{nBx} =0V	V_{CC}=2.3V	-	1.0	1.5	Ω
		I_{Ax}=100mA, V_{nBx} =2.3V		-	1.2	1.8	
		I_{Ax}=100mA, V_{nBx} =0V	V_{CC}=1.65V	-	1.3	1.9	Ω
		I_{Ax}=100mA, V_{nBx} =1.65V		-	2.0	2.8	
ΔR_{ON}	ON Resistance Match Between Channels (1,2,3)	I_{Ax}=100mA, V_{nBx} =3.15V	V_{CC}=4.5V	-	0.01	0.12	Ω
		I_{Ax}=100mA, V_{nBx} =2.1V	V_{CC}=3.0V	-	0.02	-	
		I_{Ax}=100mA, V_{nBx} =1.6V	V_{CC}=2.3V	-	0.03	-	
		I_{Ax}=100mA, V_{nBx} =1.15V	V_{CC}=1.65V	-	0.03	-	
R_{ONF}	ON Resistance Flatness (1,2,4)	I_{Ax}=100mA, V_{nBx} =0V,2.4V,4.5V	V_{CC}=4.5V	-	0.2	0.4	Ω
		I_{Ax}=100mA, V_{nBx} =0V,1.5V,3.3V	V_{CC}=3.3V	-	0.2	0.4	
		I_{Ax}=100mA, V_{nBx} =0V,1.1V,2.5V	V_{CC}=2.5V	-	0.4	0.6	
		I_{Ax}=100mA, V_{nBx} =0V, 0.7V,1.8V	V_{CC}=1.8V	-	1.0	1.4	
V_{IH}	Input High Voltage	Logic High Level	V_{CC}=1.65V	0.9	-	-	V
			V_{CC}=2.3V	1.0	-	-	
			V_{CC}=3.0V	1.1	-	-	
			V_{CC}=4.2V	1.2	-	-	
			V_{CC}=5.5V	1.3	-	-	
V_{IL}	Input Low Voltage	Logic Low Level	V_{CC}=1.65V	-	-	0.6	V
			V_{CC}=2.3V	-	-	0.6	
			V_{CC}=3.0V	-	-	0.6	
			V_{CC}=4.2V	-	-	0.8	
			V_{CC}=5.5V	-	-	0.8	
$I_{OFF(Bn)}$	Source Off Leakage Current	V_{Ax}=1V/4.5V, V_{nBx}=1V/4.5V	V_{CC}=3.0V	-20	-	+20	nA
$I_{ON(A, Bn)}$	Channel On Leakage Current	-	V_{CC}=1.65V to 5.5V	-40	-	+40	nA
I_{CC}	Quiescent Supply Current	All Channels ON or OFF, V_{nBx}=V_{CC} and GND, I_{OUT}=0A	V_{CC}=3.6V	-	0.002	0.1	µA
			V_{CC}=5.5V	-	0.002	0.1	
I_{CCT}	Increase in I_{CC} per Input	Channel Input at 2.7V	V_{CC}=4.3V	-	0.2	10.0	µA

Notes:

1. Measured by voltage drop between A and B pins at the indicated current through the device. ON resistance is determined by the lower of the voltages on two ports (Ax or nBx) x= 0 or 1, n= 0 or 1.
2. Parameter is characterized but not tested in production.
3. ΔR_{ON} = R_{ON} max – R_{ON} min. measured at identical V_{CC}, temperature and voltage levels.
4. Flatness is defined as difference between maximum and minimum value of ON resistance over the specified range of conditions.

Capacitance (1)

Symbol	Parameter	Test Conditions	Supply Voltage	Temp (℃)	Min.	Typ.	Max.	Units
C_{IN}	Control Input	f = 1 MHz	V_{CC} = 5.0V	T_A = 25℃	-	3.5	-	pF
C_{IO-B}	For Bn Port, Switch OFF				-	15.0	-	
C_{IOA-ON}	For An Port, Switch ON				-	34.0	-	

Notes:

1. Capacitance is characterized but not tested in production

Switch and AC Characteristics (1)

Parameter	Description	Test Conditions	Supply Voltage	Min	Typ	Max	Units
t_{BBM}	Break Before Make Time	See Figure 2	V_{CC} = 2.7V to 3.6V	-	10	-	ns
			V_{CC} = 4.5V to 5.5V	-	6	-	
t_{ON}	Turn on Time	See Figure 1	V_{CC} = 2.7V to 3.6V	-	16	-	
			V_{CC} = 4.5V to 5.5V	-	12	-	
t_{OFF}	Turn off Time	See Figure 1	V_{CC} = 2.7V to 3.6V	-	8	-	
			V_{CC} = 4.5V to 5.5V	-	5	-	
Q	Charge Injection	C_L = 1nF, V_{GEN} = 0V, R_{GEN}=0Ω. See Figure 3	V_{CC} = 5.0V	-	35	-	pC
			V_{CC} = 3.3V	-	25	-	
OIRR	Off Isolation(2)	R_L=50Ω, V_{GEN}=0V, R_{GEN} =0Ω, f =1MHz. See Figure 4	V_{CC} =1.65V to 5.5V	-	-70	-	dB
X_{TALK}	Crosstalk Isolation	f=1MHz, See Figure 5	V_{CC} =1.65V to 5.5V	-	-70	-	
f_{3dB}	–3dB Bandwidth	See Figure 8	V_{CC} =1.65V to 5.5V	-	150	-	MHz
T_{HD}	Total Harmonic Distortion	R_L=600Ω, V_{IN}=0.5Vpp, f=20Hz to 20kHz See Figure 9	V_{CC} =2.7V to 4.2V	-	0.015	-	%

Notes:

1. Guaranteed by design.
2. Off Isolation = 20 Log_{10} [V_{nBx} /V_{Ax}] and is measured in dB.

Test Circuits and Timing Diagrams

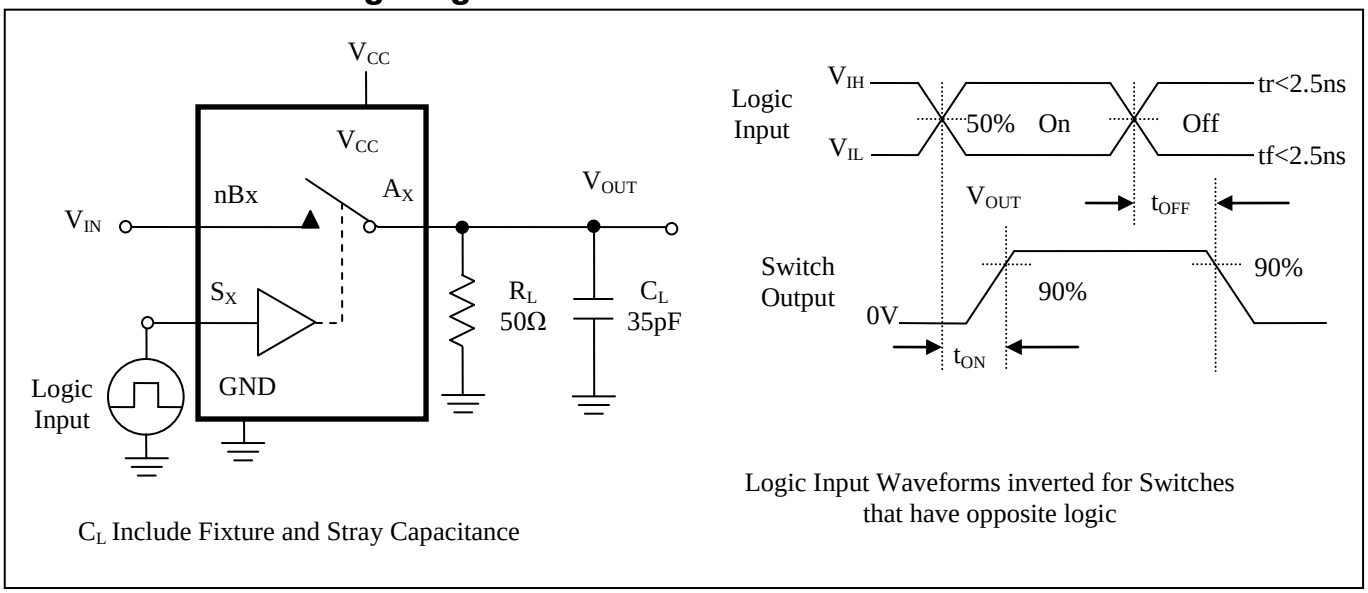


Figure 1. Turn ON/OFF Timing

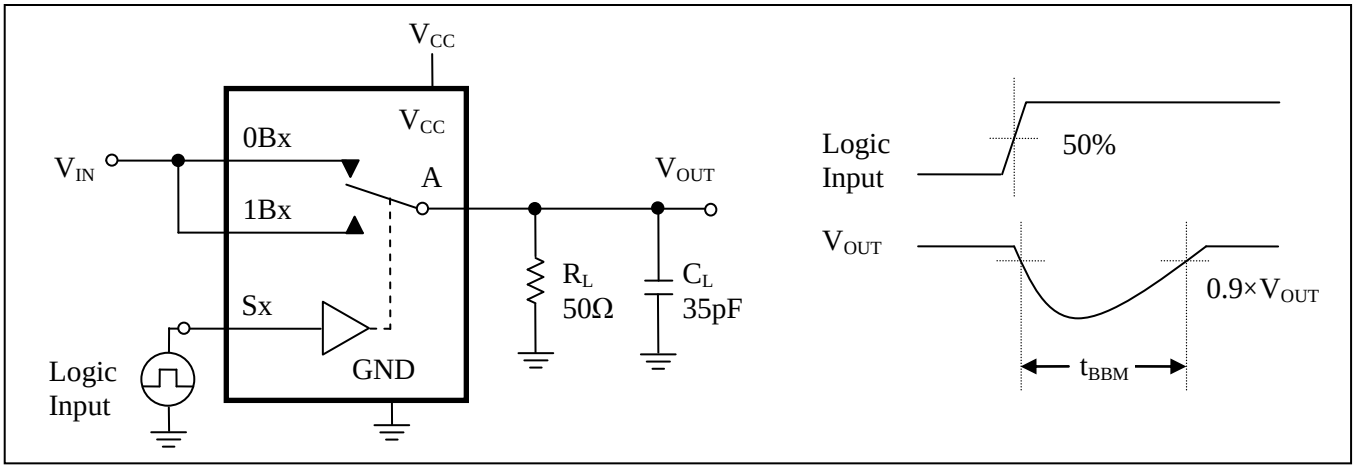


Figure 2. Break Before Make Interval Timing

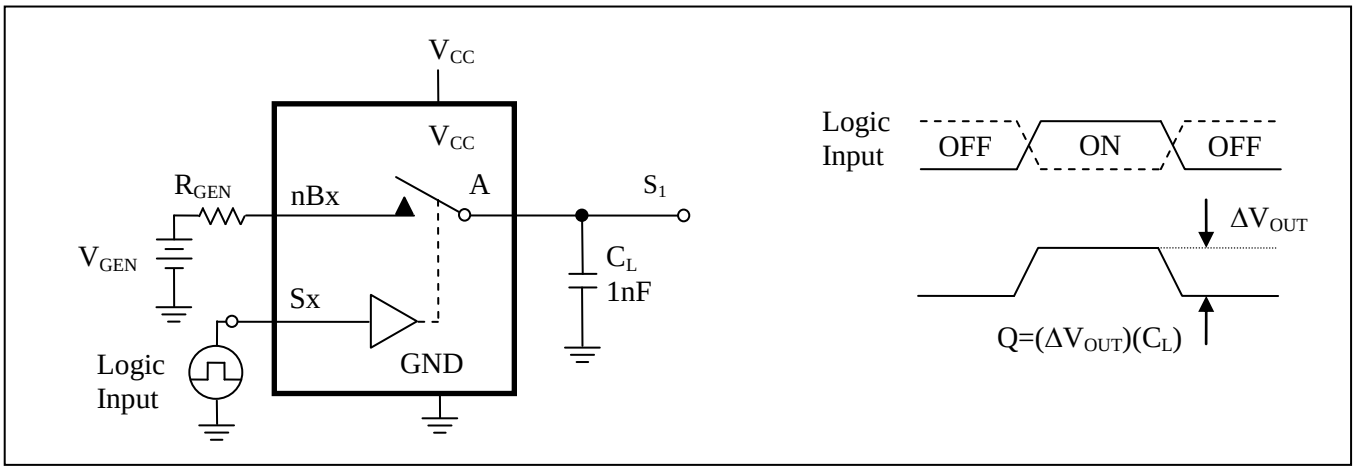


Figure 3. Charge Injection Test

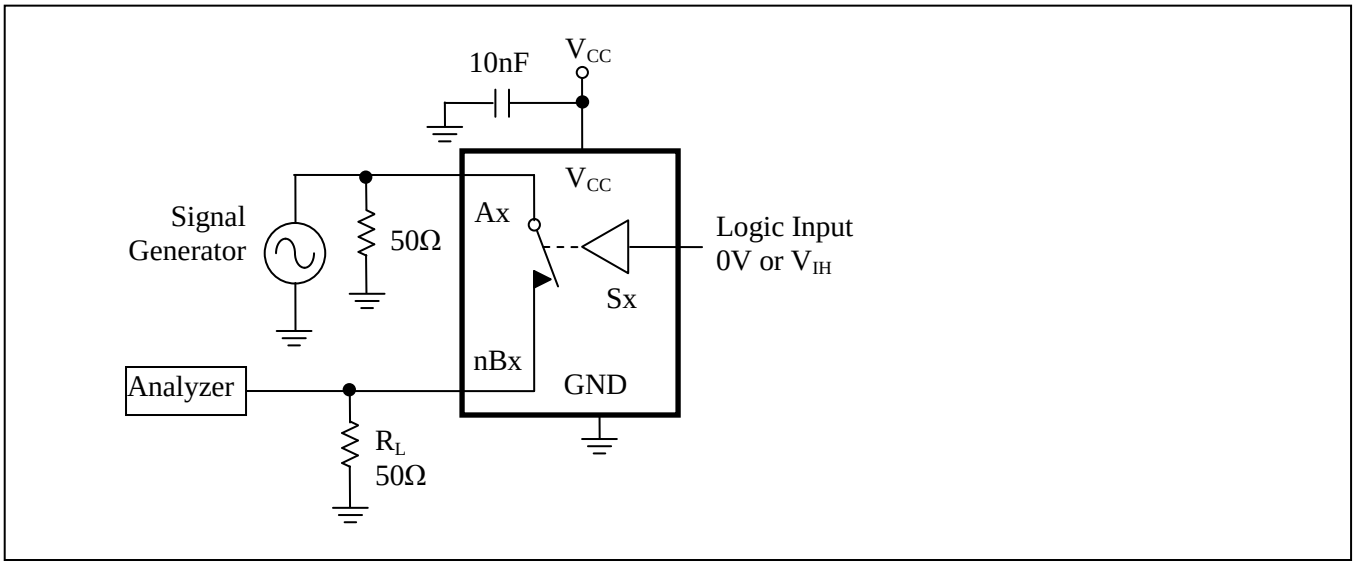


Figure 4. Off Isolation

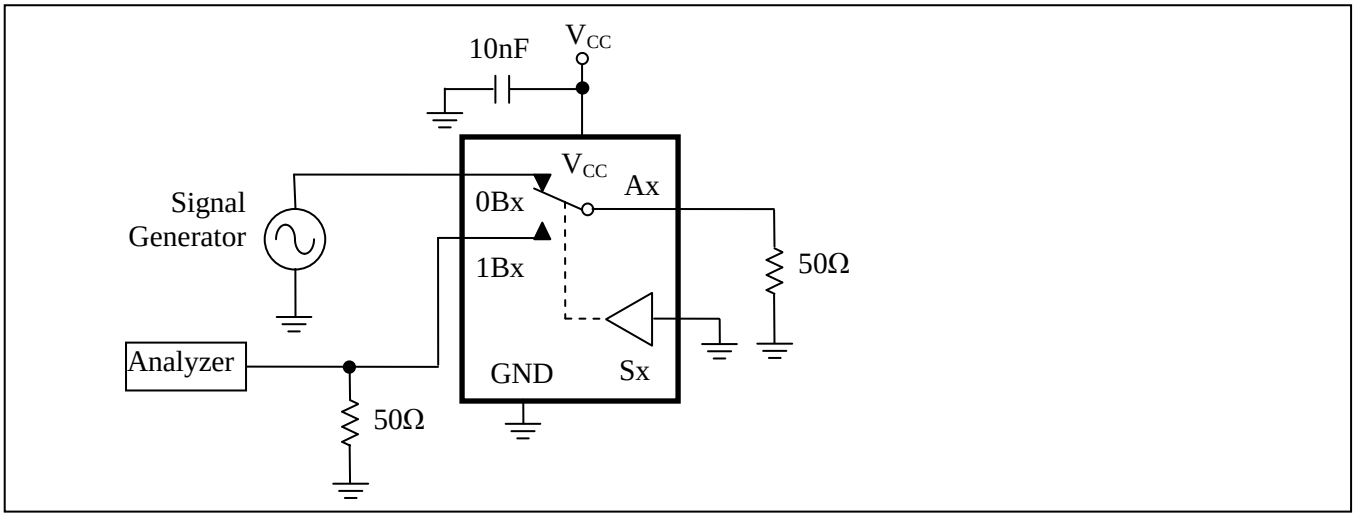


Figure 5. Crosstalk

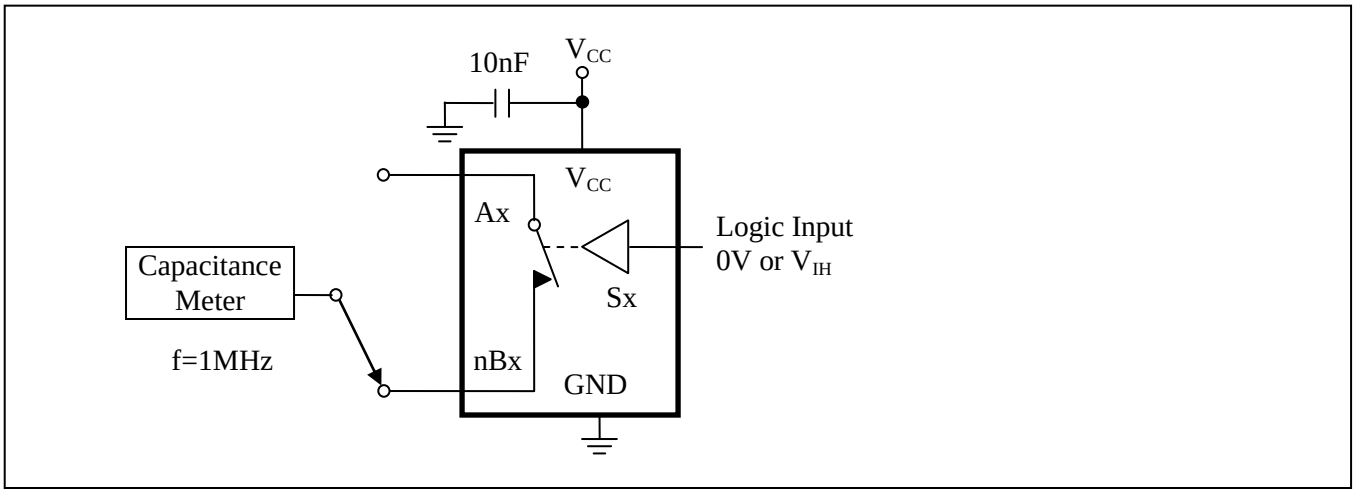


Figure 6. Channel Off Capacitance

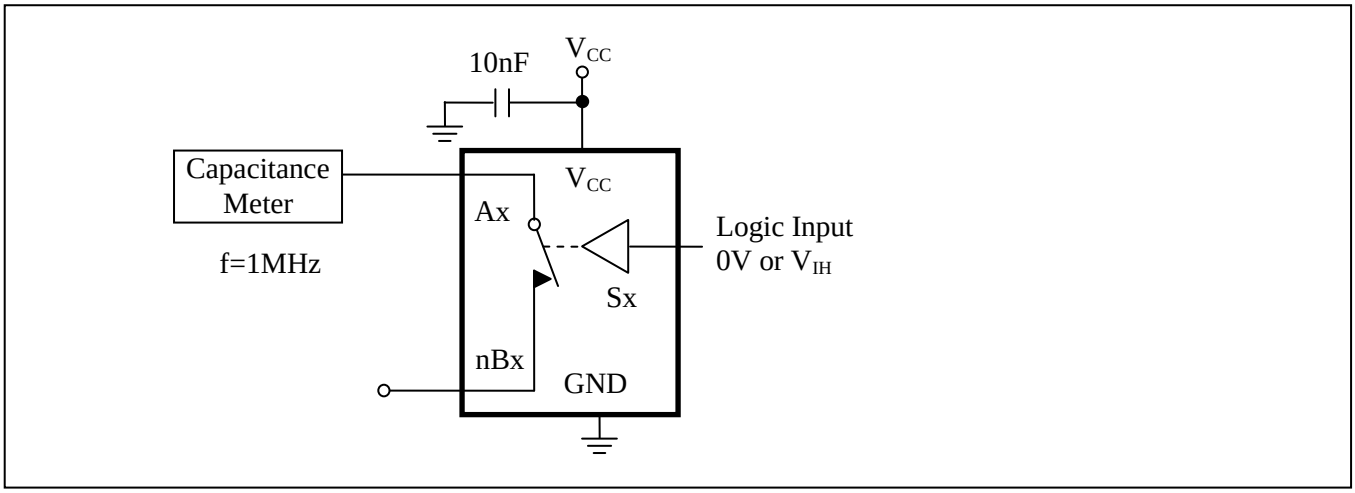


Figure 7. Channel On Capacitance

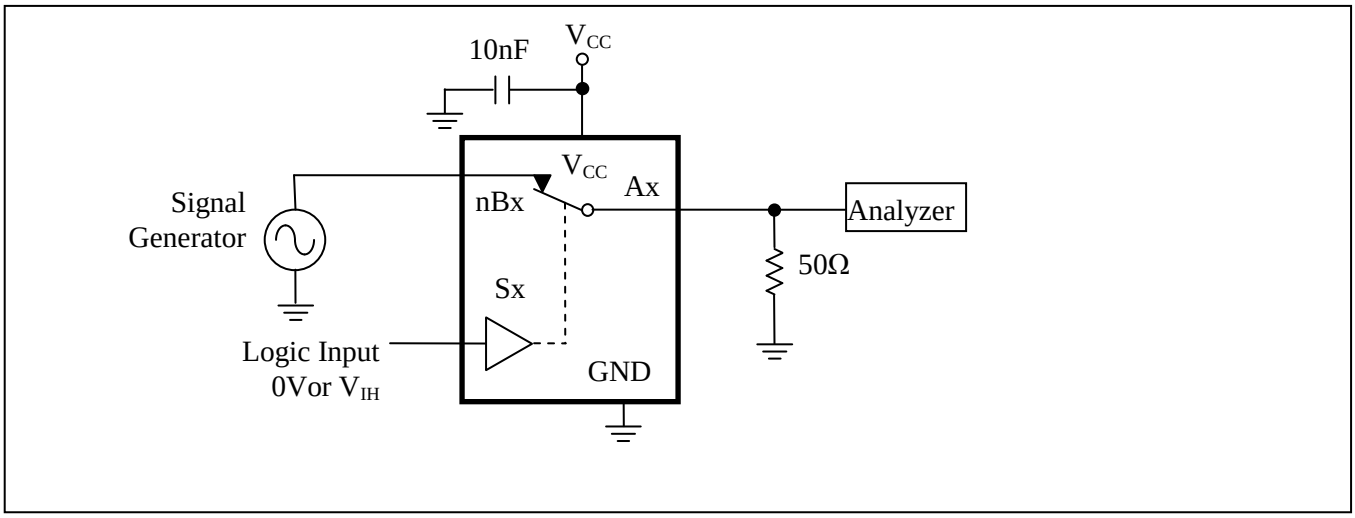


Figure 8. Bandwidth

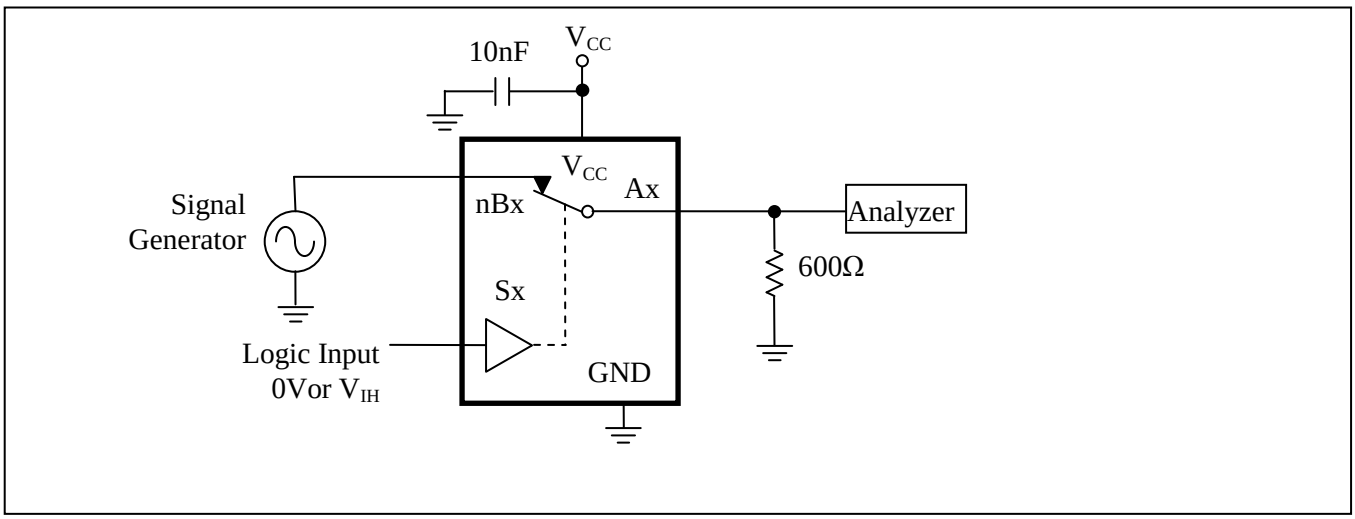
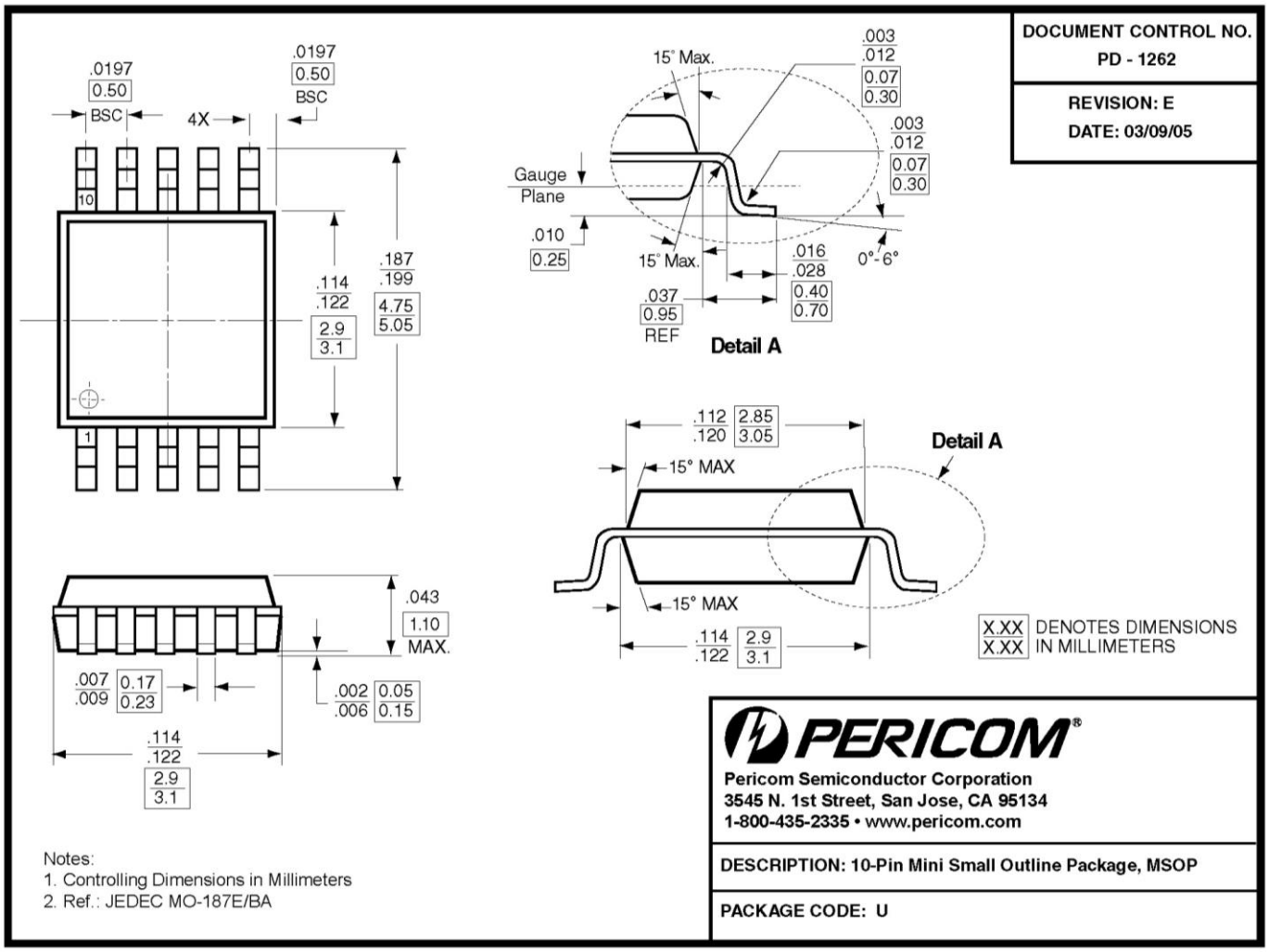


Figure 9. Harmonic Distortion

Packaging Mechanical

10-MSOP (U)



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Ordering Information

Part Number	Package Code	Package Description
PI5A23159UEX	U	10-Pin, Mini Small Outline Package (MSOP)

Notes:

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